NSN 5961-01-352-1808

Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-352-1808 **Inclosure Material:** Metal **Overall Length:** Between 0.645 inches and 0.665 inches **Overall Height:** Between 0.190 inches and 0.200 inches Overall Width: Between 0.410 inches and 0.422 inches **Component Name And Quantity:** 2 semiconductor device diode **Mounting Method: Terminal Features Provided:** Electrostatic sensitive **Semiconductor Material:** Silicon all semiconductor device diode **Voltage Rating In Volts Per Characteristic:** 150.0 reverse voltage, peak all semiconductor device diode **Current Rating Per Characteristic:** 8.00 amperes forward current, average absolute all semiconductor device diode and 60.00 amperes forward current, average preset all semiconductor device diode **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius ambient air **Special Features:** All semiconductor device diode junction pattern arrangement: pn **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: A110a0